Power MOSFET

60 V, 295 mA, Dual N-Channel with ESD Protection, SC-88

Features

- Low R_{DS(on)}
- Low Gate Threshold
- Low Input Capacitance
- ESD Protected Gate
- NV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- This is a Pb-Free Device

Applications

- Low Side Load Switch
- DC-DC Converters (Buck and Boost Circuits)

MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Parame	Symbol	Value	Unit			
Drain-to-Source Voltage	V_{DSS}	60	V			
Gate-to-Source Voltage	V_{GS}	±20	V			
Continuous Drain	Steady	T _A = 25°C	I _D	295	mA	
Current (Note 1)	State	T _A = 85°C		212		
	t ≤ 5 s	T _A = 25°C		304		
		T _A = 85°C		219		
Power Dissipation (Note 1)	Steady State	T _A = 25°C	P _D	250	mW	
	t ≤ 5 s			266		
Pulsed Drain Current	t _p =	= 10 μs	I _{DM}	900	mA	
Operating Junction and S	T _J , T _{STG}	-55 to 150	°C			
Source Current (Body Did	I _S	210	mA			
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			T _L	260	°C	
Gate-Source ESD Rating	ESD _{HBM}	2000	V			
Gate-Source ESD Rating (MM)			ESD _{MM}	200	V	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Ambient - Steady State	$R_{\theta JA}$	467	°C/W
Junction-to-Ambient - t ≤ 5 s	$R_{\theta JA}$	412	
Junction-to-Lead - Steady State	$R_{ heta JL}$	252	

Surface mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces).

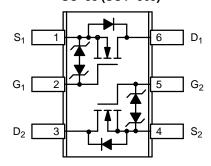


ON Semiconductor®

www.onsemi.com

V _{(BR)DSS}	R _{DS(on)} MAX	I _D Max	
60 V	1.6 Ω @ 10 V	295 mA	
	2.5 Ω @ 4.5 V	293 IIIA	

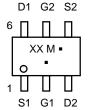
SC-88 (SOT-363)



Top View

MARKING DIAGRAM & PIN ASSIGNMENT





XX = Device CodeM = Date CodePb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information ion page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_{.I} = 25°C unless otherwise stated)

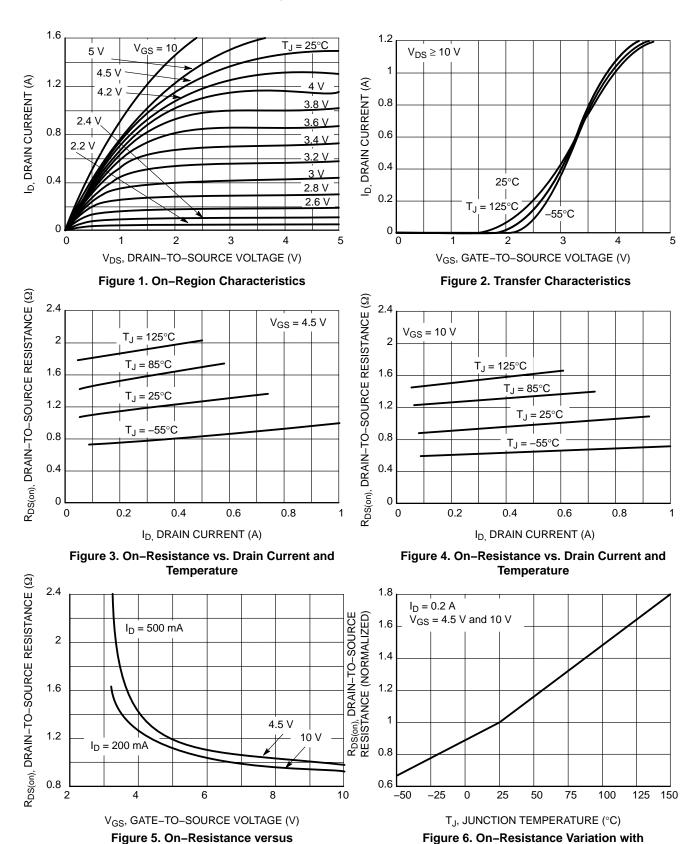
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS			•				
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		60			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J	I _D = 250 μA, ref to 25°C			92		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$, $V_{DS} = 60 V$	T _J = 25°C			1.0	μΑ
			T _J = 125°C			500	
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{C}$	_{iS} = ±20 V			±10	μΑ
ON CHARACTERISTICS (Note 2)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{D}$, = 250 μΑ	1.0	1.7	2.5	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				4.0		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 500 \text{ mA}$			1.0	1.6	Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 200 \text{ mA}$			1.2	2.5	
Forward Transconductance	9FS	V _{DS} = 5 V, I _D = 200 mA			80		S
Gate Resistance	R_{G}				536		Ω
CHARGES AND CAPACITANCES							•
Input Capacitance	C _{ISS}	$V_{GS} = 0 \text{ V, f} = 1.0 \text{ MHz,}$ $V_{DS} = 20 \text{ V}$			26		pF
Output Capacitance	C _{OSS}				4.4		
Reverse Transfer Capacitance	C _{RSS}	- 55			2.5		
Total Gate Charge	$Q_{G(TOT)}$				0.9		nC
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 4.5 V, V	_{DS} = 25 V,		0.2		
Gate-to-Source Charge	Q_{GS}	$I_{D} = 200$	mA		0.3		
Gate-to-Drain Charge	Q_{GD}				0.28		
SWITCHING CHARACTERISTICS (No	ote 3)						
Turn-On Delay Time	t _{d(on)}				22		ns
Rise Time	t _r	$V_{GS} = 4.5 \text{ V}, V_{DD} = 25 \text{ V},$ $I_{D} = 200 \text{ mA}, R_{G} = 25 \Omega$			34		
Turn-Off Delay Time	t _{d(off)}				34		
Fall Time	t _f				32		
DRAIN-SOURCE DIODE CHARACTE	RISTICS						
Forward Diode Voltage	V_{SD}	V _{GS} = 0 V,	T _J = 25°C		0.8	1.2	V
		$I_S = 200 \text{ mA}$	T _J = 85°C		0.7		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Pulse Test: pulse width ≤ 300 μs, duty cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperatures.

TYPICAL PERFORMANCE CURVES

(T_J = 25°C unless otherwise noted)



Gate-to-Source Voltage

Temperature

TYPICAL PERFORMANCE CURVES

(T_J = 25°C unless otherwise noted)

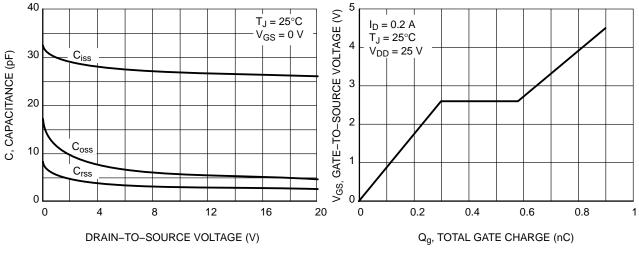


Figure 7. Capacitance Variation

Figure 8. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

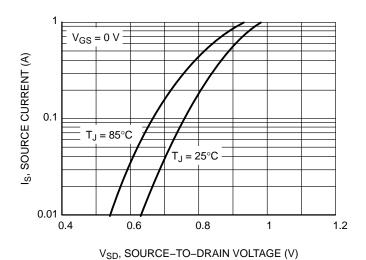


Figure 9. Diode Forward Voltage vs. Current

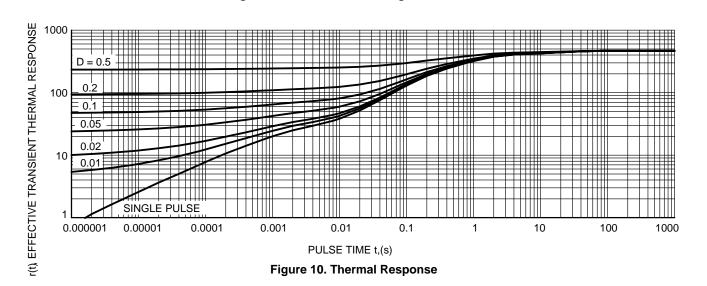


Table 1. ORDERING INFORMATION

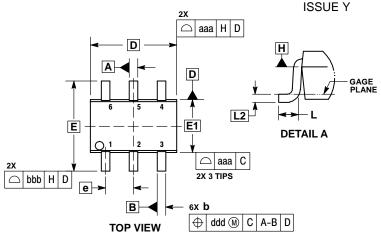
Part Number	Marking (XX)	Package	Shipping [†]
NTJD5121NT1G	TF	SC-88 (Pb-Free)	3000 / Tape & Reel
NTJD5121NT2G	TF	SC-88 (Pb-Free)	3000 / Tape & Reel
NVJD5121NT1G	VTF	SC-88 (Pb-Free)	3000 / Tape & Reel

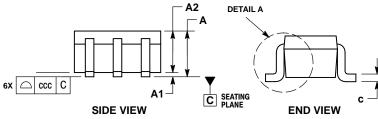
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363

CASE 419B-02





NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH.
- PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRU-SIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF

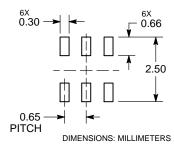
- THE PLASTIC BODY AND DATUM H.
 DATUMS A AND B ARE DETERMINED AT DATUM H.
 DIMENSIONS b AND 6 APPLY TO THE FLAT SECTION OF THE
 LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
- DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION 6 AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α			1.10			0.043	
A1	0.00		0.10	0.000		0.004	
A2	0.70	0.90	1.00	0.027	0.035	0.039	
b	0.15	0.20	0.25	0.006	0.008	0.010	
С	0.08	0.15	0.22	0.003	0.006	0.009	
D	1.80	2.00	2.20	0.070	0.078	0.086	
E	2.00	2.10	2.20	0.078	0.082	0.086	
E1	1.15	1.25	1.35	0.045	0.049	0.053	
е	0.65 BSC			0.026 BSC			
L	0.26	0.36	0.46	0.010	0.014	0.018	
L2	0.15 BSC			0.006 BSC			
aaa	0.15			0.006			
bbb	0.30			0.012			
ccc	0.10			0.004			
ddd	0.10				0.004		

STYLE 26: PIN 1. SOURCE 1

- GATE 1
 - 3. DRAIN 2
 - SOURCE 2
 - GATE 2 DRAIN 1

RECOMMENDED **SOLDERING FOOTPRINT**



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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